



InGaP HBT GAIN BLOCK MMIC AMPLIFIER, DC - 4 GHz

Typical Applications

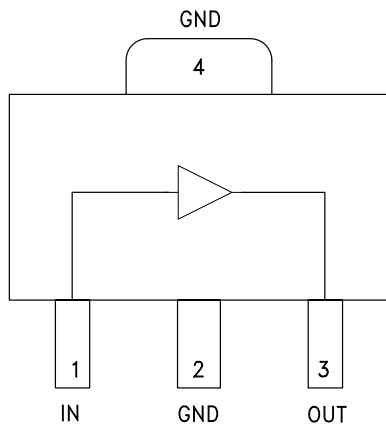
The HMC589ST89 / HMC589ST89E is ideal for:

- Cellular / PCS / 3G
- Fixed Wireless & WLAN
- CATV, Cable Modem & DBS
- Microwave Radio & Test Equipment
- IF & RF Applications

Features

- P1dB Output Power: +21 dBm
- Gain: 21 dB
- Output IP3: +33 dBm
- Single Supply: +5V
- Industry Standard SOT89 Package

Functional Diagram



General Description

The HMC589ST89 & HMC589ST89E are InGaP HBT Gain Block MMIC SMT amplifiers covering DC to 4 GHz and packaged in an industry standard SOT89. The amplifier can be used as a cascadable 50 Ohm RF or IF gain stage as well as a LO or PA driver with up to +19 dBm P1dB output power for cellular/3G, FWA, CATV, microwave radio and test equipment applications. The HMC589ST89(E) offers 20 dB gain and +33 dBm output IP3 at 1 GHz while requiring only 82 mA from a single positive supply. The HMC589ST89(E) InGaP HBT gain block offers excellent output power and gain stability over temperature.

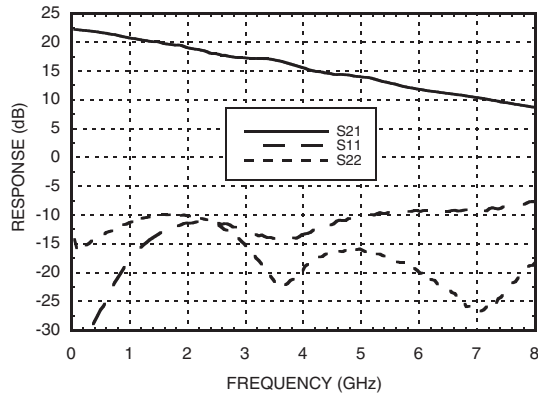
Electrical Specifications, $V_s = 5V$, $R_{bias} = 1.8 \text{ Ohm}$, $T_A = +25^\circ \text{ C}$

Parameter		Min.	Typ.	Max.	Units
Gain	DC - 1.0 GHz	19	21	25	dB
	1.0 - 2.0 GHz	16	19	23	dB
	2.0 - 3.0 GHz	14	17	22	dB
	3.0 - 4.0 GHz	13	15	20	dB
Gain Variation Over Temperature	DC - 5 GHz		0.008		dB/ °C
Input Return Loss	DC - 1.0 GHz	13	17		dB
	1.0 - 4.0 GHz	8	11		dB
Output Return Loss	DC - 1.0 GHz	8	12		dB
	1.0 - 4.0 GHz	7	10		dB
Reverse Isolation	DC - 4 GHz		23		dB
Output Power for 1 dB Compression (P1dB)	0.5 - 1.0 GHz	17.5	21		dBm
	1.0 - 2.0 GHz	16	19		dBm
	2.0 - 3.0 GHz	16	19		dBm
	3.0 - 4.0 GHz	14.5	17.5		dBm
Output Third Order Intercept (IP3) (Pout= 0 dBm per tone, 1 MHz spacing)	0.5 - 1.0 GHz		33		dBm
	1.0 - 2.0 GHz		32		dBm
	2.0 - 3.0 GHz		30.5		dBm
	3.0 - 4.0 GHz		29		dBm
Noise Figure	DC - 2.0 GHz		4.0		dB
	2.0 - 4.0 GHz		4.5		dB
Supply Current (Icq)			82	102	mA

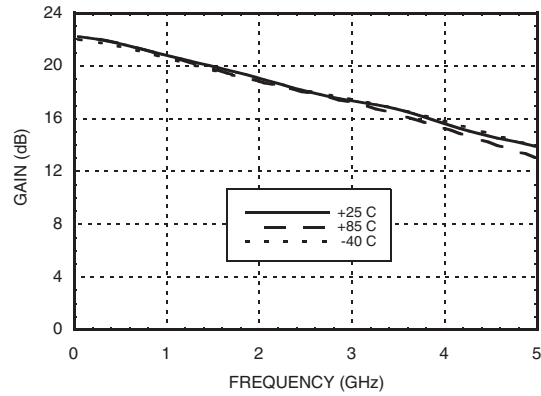
Note: Data taken with broadband bias tee on device output.

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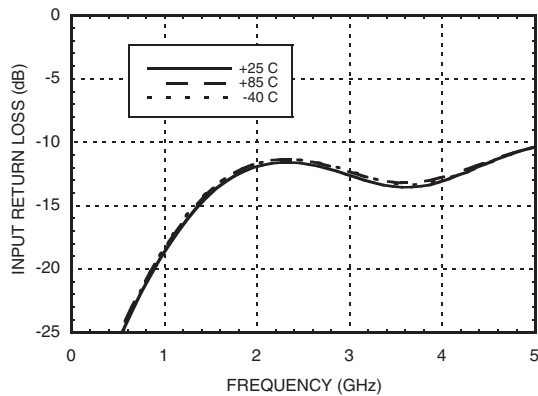
Broadband Gain & Return Loss



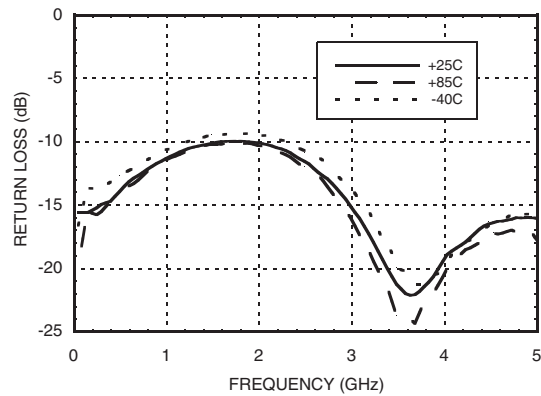
Gain vs. Temperature



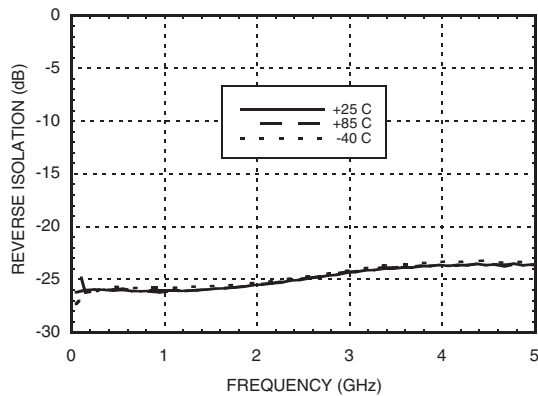
Input Return Loss vs. Temperature



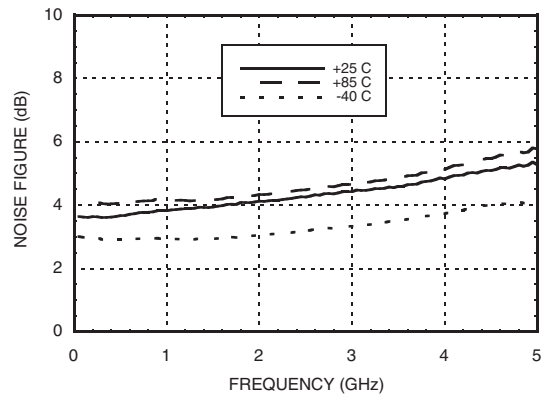
Output Return Loss vs. Temperature



Reverse Isolation vs. Temperature



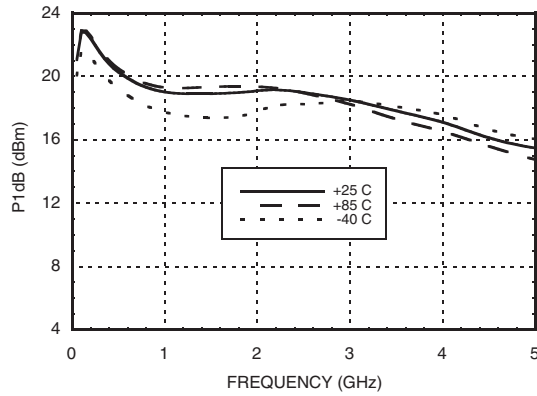
Noise Figure vs. Temperature



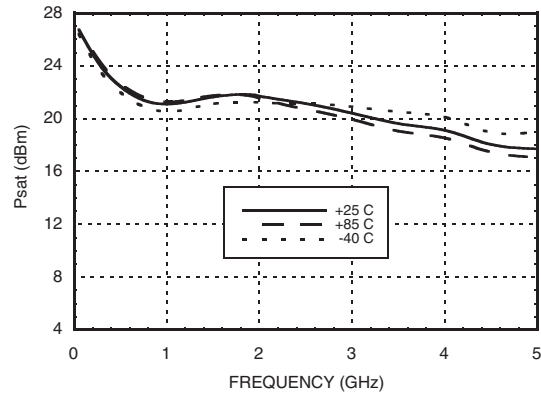


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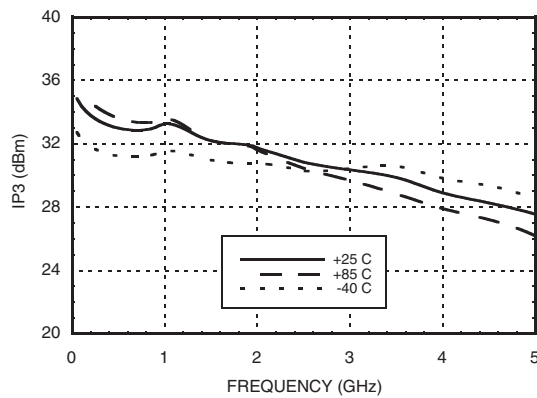
P1dB vs. Temperature



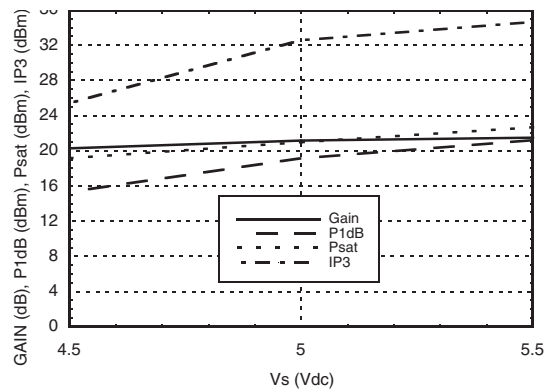
Psat vs. Temperature



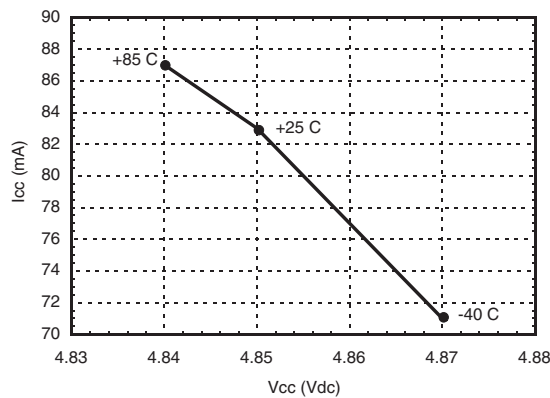
Output IP3 vs. Temperature



**Gain, Power & OIP3 vs. Supply Voltage
@ 850 MHz, Rbias = 1.8 Ohms**



**Vcc vs. Icc Over Temperature for
Fixed Vs= 5V, RBIAS= 1.8 Ohms**



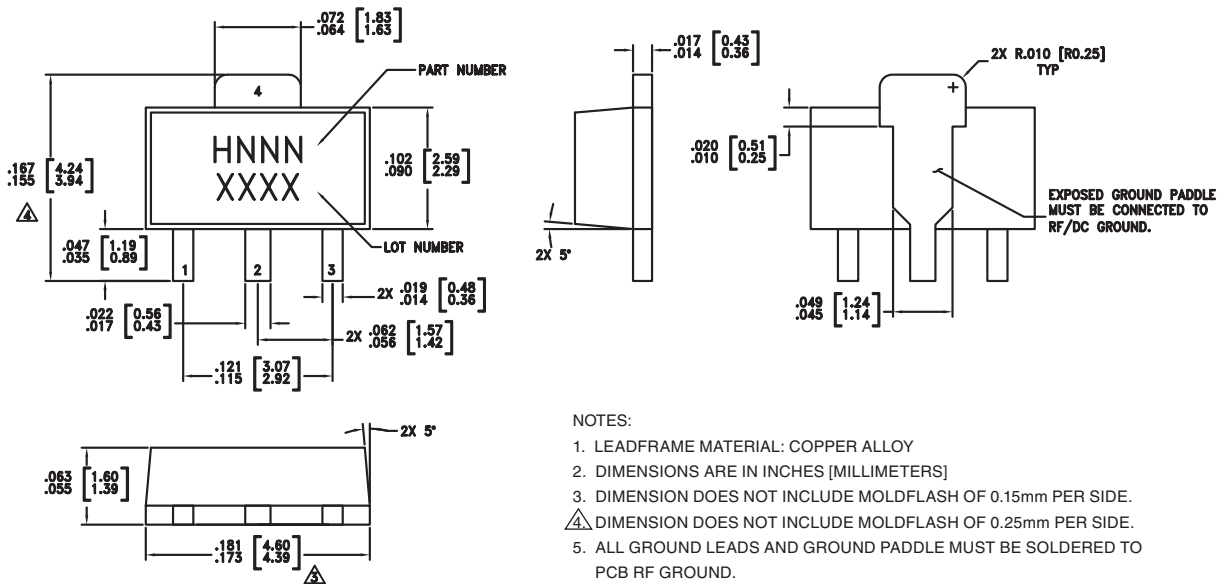
Absolute Maximum Ratings

Collector Bias Voltage (Vcc)	+5.5 Vdc
RF Input Power (RFIN)(Vcc = +5 Vdc)	+10 dBm up to 1 GHz +8 dBm from 1-4 GHz
Junction Temperature	150 °C
Continuous Pdiss (T = 85 °C) (derate 8.4 mW/°C above 85 °C)	0.546 W
Thermal Resistance (junction to ground paddle)	119 °C/W
Storage Temperature	-65 to +150 °C
Operating Temperature	-40 to +85 °C
ESD Sensitivity (HBM)	Class 1C



ELECTROSTATIC SENSITIVE DEVICE
OBSERVE HANDLING PRECAUTIONS

Outline Drawing



Package Information

Part Number	Package Body Material	Lead Finish	MSL Rating	Package Marking ^[3]
HMC589ST89	Low Stress Injection Molded Plastic	Sn/Pb Solder	MSL1 ^[1]	H589 XXXX
HMC589ST89E	RoHS-compliant Low Stress Injection Molded Plastic	100% matte Sn	MSL1 ^[2]	H589 XXXX

[1] Max peak reflow temperature of 235 °C

[2] Max peak reflow temperature of 260 °C

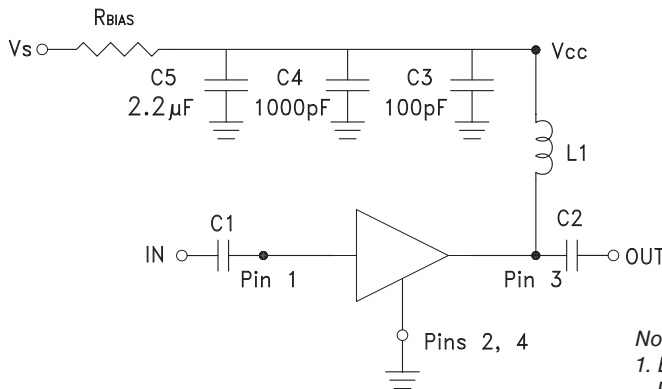
[3] 4-Digit lot number XXXX

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Pin Descriptions

Pin Number	Function	Description	Interface Schematic
1	IN	This pin is DC coupled. An off chip DC blocking capacitor is required.	
3	OUT	RF output and DC Bias (Vcc) for the output stage.	
2, 4	GND	These pins and package bottom must be connected to RF/DC ground.	

Application Circuit



- Note:**
1. External blocking capacitors are required on RFIN and RFOUT.
 2. RBIAS provides DC bias stability over temperature.

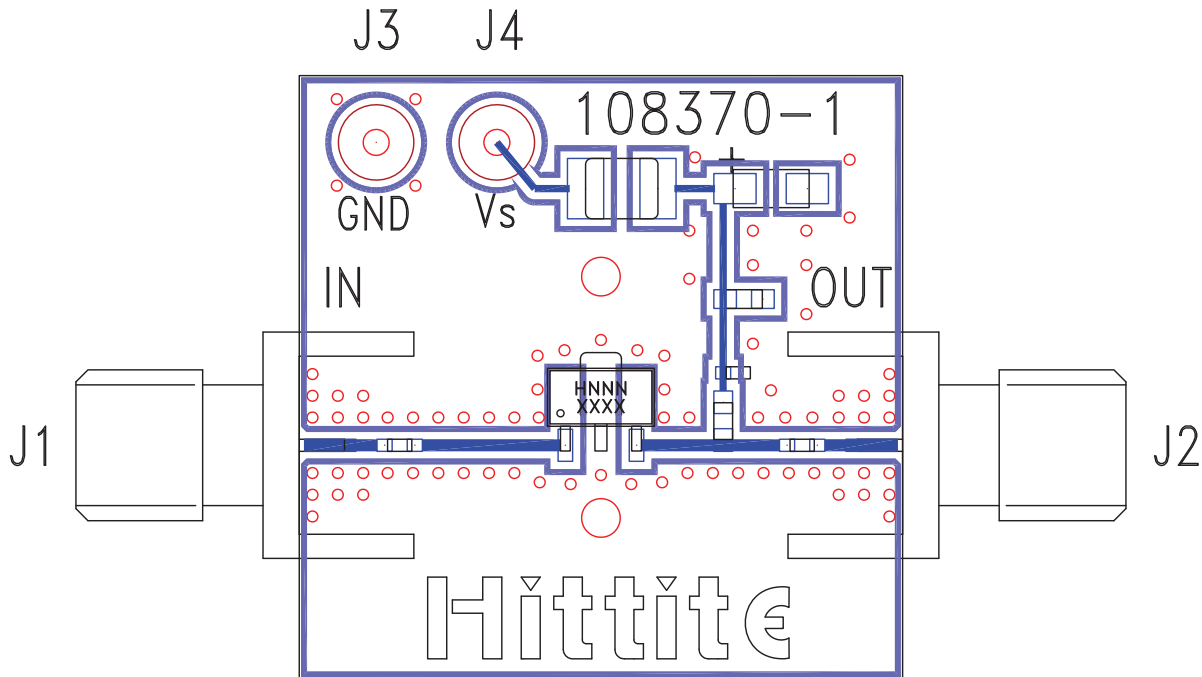
Recommended Bias Resistor Values for $I_{cc} = 88 \text{ mA}$, $R_{bias} = (V_s - V_{cc}) / I_{cc}$

Supply Voltage (Vs)	5V	6V	8V
RBIAS VALUE	1.8 Ω	13 Ω	38 Ω
RBIAS POWER RATING	1/8 W	1/4 W	1/2 W

Recommended Component Values for Key Application Frequencies

Component	Frequency (MHz)						
	50	900	1900	2200	2400	3500	4000
L1	270 nH	56 nH	24 nH	24 nH	15 nH	8.2 nH	8.2 nH
C1, C2	0.01 μF	100 pF	100 pF	100 pF	100 pF	100 pF	100 pF

Evaluation PCB



List of Materials for Evaluation PCB 116405 [1]

Item	Description
J1 - J2	PCB Mount SMA Connector
J3 - J4	DC Pin
C1, C2	Capacitor, 0402 Pkg.
C3	100 pF Capacitor, 0402 Pkg.
C4	1000 pF Capacitor, 0603 Pkg.
C5	2.2 μ F Capacitor, Tantalum
R1	Resistor, 1206 Pkg.
L1	Inductor, 0603 Pkg.
U1	HMC589ST89 / HMC589ST89E
PCB [2]	108370 Evaluation PCB

[1] Reference this number when ordering complete evaluation PCB

[2] Circuit Board Material: Rogers 4350

[3] Evaluation board tuned for 1.9 GHz operation

The circuit board used in the final application should use RF circuit design techniques. Signal lines should have 50 ohm impedance while the package ground leads and package bottom should be connected directly to the ground plane similar to that shown. A sufficient number of via holes should be used to connect the top and bottom ground planes. The evaluation board should be mounted to an appropriate heat sink. The evaluation circuit board shown is available from Hittite upon request.